
2SC2610

Silicon NPN Triple Diffused

HITACHI

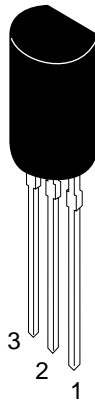
ADE-208-1068 (Z)
1st. Edition
Mar. 2001

Application

- High voltage amplifier
- TV Video output

Outline

TO-92MOD



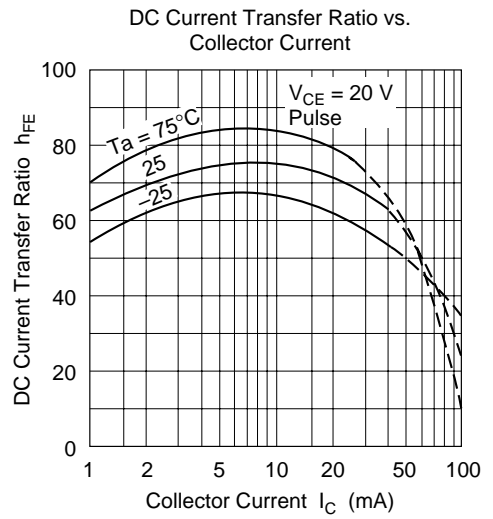
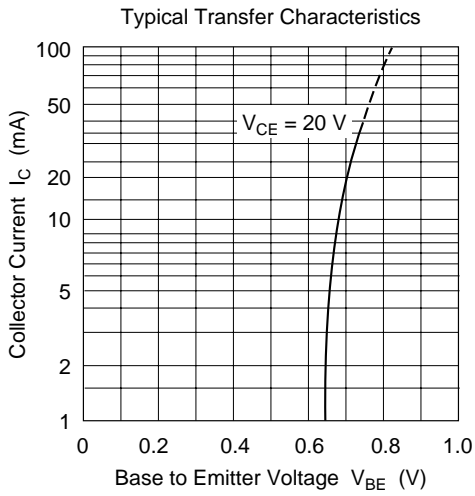
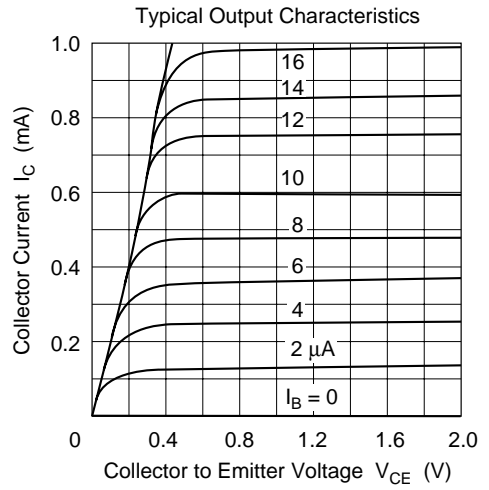
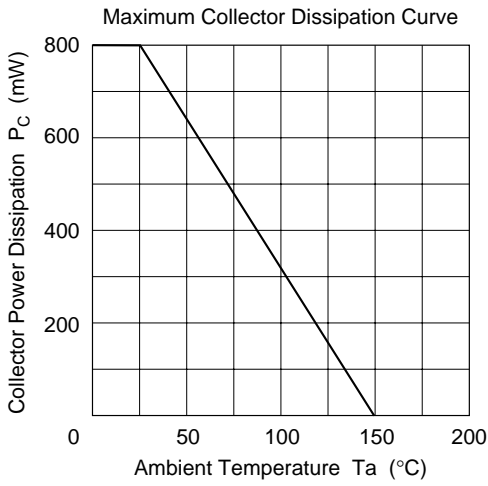
1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

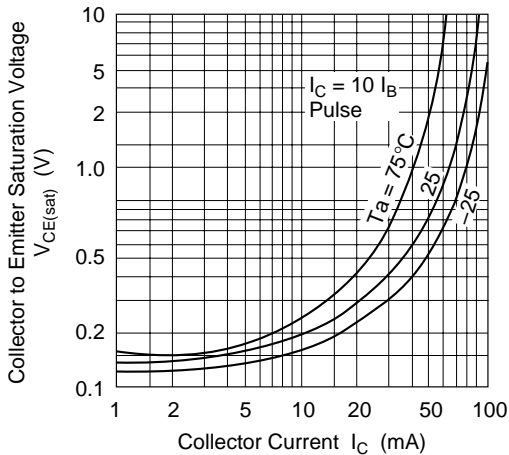
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	300	V
Collector to emitter voltage	V_{CEO}	300	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_{C}	100	mA
Collector power dissipation	P_{C}	800	mW
Junction temperature	T_{j}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

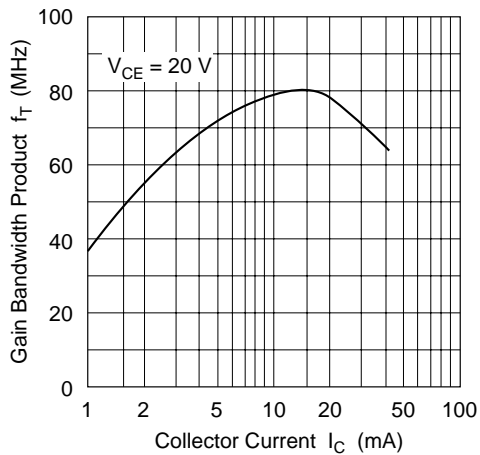
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	300	—	—	V	$I_{\text{C}} = 10 \mu\text{A}$, $I_{\text{E}} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	300	—	—	V	$I_{\text{C}} = 1 \text{ mA}$, $R_{\text{BE}} = \infty$
Emitter to base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	5	—	—	V	$I_{\text{E}} = 10 \mu\text{A}$, $I_{\text{C}} = 0$
Collector cutoff current	I_{CEO}	—	—	1.0	μA	$V_{\text{CE}} = 250 \text{ V}$, $R_{\text{BE}} = \infty$
DC current transfer ratio	h_{FE}	30	—	200		$V_{\text{CE}} = 20 \text{ V}$, $I_{\text{C}} = 20 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	—	—	1.5	V	$I_{\text{C}} = 20 \text{ mA}$, $I_{\text{B}} = 2 \text{ mA}$
Gain bandwidth product	f_{T}	50	80	—	MHz	$V_{\text{CE}} = 20 \text{ V}$, $I_{\text{C}} = 20 \text{ mA}$
Collector output capacitance	C_{ob}	—	—	4.0	pF	$V_{\text{CB}} = 20 \text{ V}$, $I_{\text{E}} = 0$, $f = 1 \text{ MHz}$



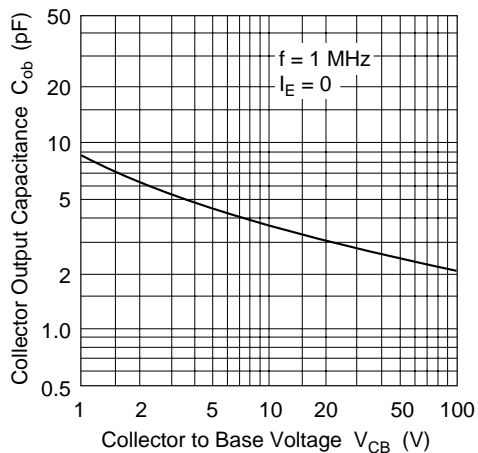
Collector to Emitter Saturation Voltage vs. Collector Current



Gain Bandwidth Product vs. Collector Current

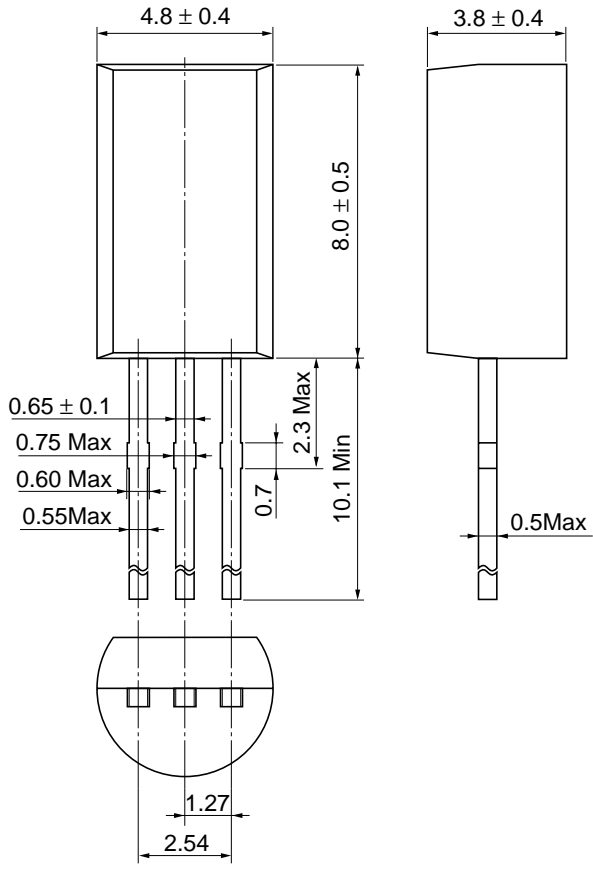


Collector Output Capacitance vs. Collector to Base Voltage



Package Dimensions

As of January, 2001
Unit: mm



Hitachi Code	TO-92 Mod
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.35 g

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